NSN 5961-00-192-6263

Thyristor Semiconductor Device - Page 1 of 1



| View Online at https://aerobasegroup.com/nsn/5961-00-192-6263 |
|---|
| Inclosure Material: |
| Metal |
| Overall Length: |
| 0.210 inches |
| Terminal Length: |
| 0.500 inches |
| Overall Diameter: |
| 0.230 inches |
| Internal Configuration: |
| Junction contact |
| Electrode Internally-electrically Connected To Case: |
| Gate |
| Mounting Method: |
| Terminal |
| Terminal Circle Diameter: |
| 0.100 inches |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 30.0 breakover voltage, dc |
| Current Rating Per Characteristic: |
| 0.20 amperes source cutoff current |
| Maximum Operating Tempurature Per Measurement Point: |
| 150.0 degrees celsius ambient air |
| Special Features: |
| Junction pattern arrangement: pnpn |
| Terminal Type And Quantity: |
| 3 uninsulated wire lead |
| Specification Data: |
| 80131-release5472 professional/industrial association specification |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |